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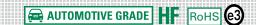


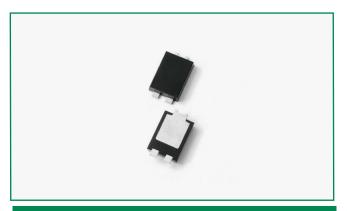




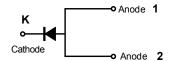
## Schottky Barrier Rectifier DST1045S-A, 10A, 45V, TO-277B, Single

### DST1045S-A





### Pin out



### **Description**

Littelfuse DST series Ultra Low VF Schottky Barrier Rectifier is designed to meet the general requirements of automotive applications by providing high temperature, low leakage and low VF products.

It is suitable for high frequency switching mode power supply applications, as free-wheeling and polarity protection diodes.

#### **Features**

- Ultra low forward voltage drop
- High frequency operation
- High junction temperature capability
- Hi reliability application and automotive grade AEC-Q101 qualified
- Trench MOS Barrier Schottky technology
- Single die in TO-277B Package

### **Applications**

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

### **Maximum Ratings**

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V <sub>RWM</sub>	-	45	V
Average Forward Current *	I <sub>F(AV)</sub>	50% duty cycle @T <sub>L</sub> = 125 °C rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

<sup>\*</sup> Mounted on 30 mm x 30 mm pad areas aluminum PCB

### **Electrical Characteristics**

Parameters	Symbol	Test Conditions	Тур	Max	Unit	
Forward Voltage Drop *	V	@5A, Pulse, T <sub>J</sub> = 25 °C	0.43	0.51		
	V <sub>F1</sub>	@10A, Pulse, T <sub>J</sub> = 25 °C	0.49	0.57	V	
	V	@5A, Pulse, T <sub>J</sub> = 125 °C	0.32	0.43		
	$V_{F2}$	@10A, Pulse, T <sub>J</sub> = 125 °C	0.41	0.50		
Reverse Current *	I <sub>R1</sub>	$@V_R = rated V_{R_i} T_J = 25 \text{ °C}$	0.003	0.019	mA	
neverse Current	I <sub>R2</sub>	$@V_R = rated V_{R,} T_J = 125 °C$	5	15	] '''A	
Junction Capacitance	C <sub>T</sub>	$@V_{B} = 5V, T_{C} = 25 \text{ °C}, f_{SIG} = 1MHz$	656	-	pF	

<sup>\*</sup> Pulse Width < 300 $\mu$ s, Duty Cycle <2%

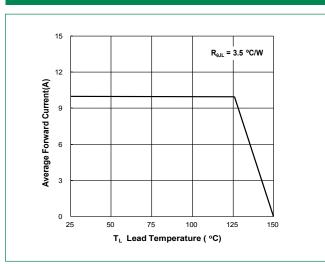
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### **Thermal-Mechanical Specifications**

Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	$T_{J}$		-55 to +150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C
Thermal Resistance Junction to Ambient	R <sub>eJA</sub>	DC operation	75	°C/W
Typical Thermal Resistance Junction to Lead	R <sub>⊕JL</sub> *	DC operation	3.5	°C/W
Approximate Weight	wt		0.08	g
Case Style		TO-277B		

<sup>(1)</sup> Free air, mounted on recommended copper pad area; thermal resistance  $R_{\Theta^{J\!A}}$  - junction to ambient

### **Figure 1: Forward Current Derating Curve**



**Figure 2: Forward Power Loss Characteristics** 

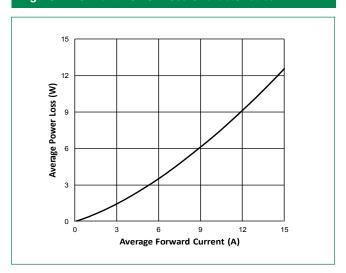


Figure 3: Typical Instantaneous Forward Voltage Characteristics

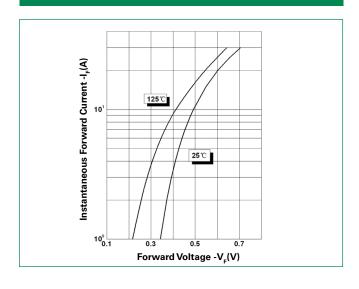
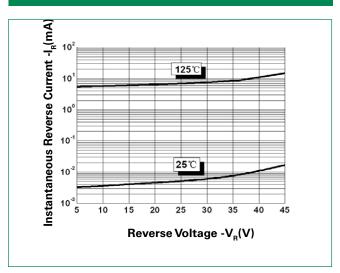


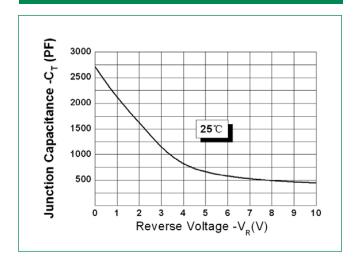
Figure 4: Typical Reverse Characteristics



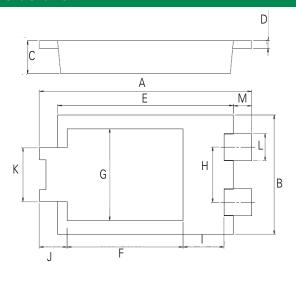
<sup>(2)</sup> Mounted on 30 mm x 30 mm pad areas aluminum PCB; thermal resistance R<sub>OJI</sub> - junction to lead

<sup>\*</sup>Lead temperature monitored at the cathode pin

### Figure 5: Typical Junction Capacitance

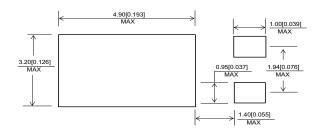


### **Dimensions-TO-277B**



Symbol	Millimeters				
	Min	Тур	Max		
Α	6.30	6.50	6.70		
В	3.88	3.98	4.08		
С	0.95	1.10	1.25		
D	0.20	0.25	0.30		
E	5.28	5.38	5.48		
F	3.40	3.55	3.70		
G	2.90	3.05	3.20		
Н	1.74	1.84	1.94		
ı	1.10	1.25	1.40		
J	-	0.85	-		
K	1.70	1.80	1.90		
L	0.85	0.90	0.95		
M	-	0.56	-		

### **Mounting Pad Layout**



### **Part Numbering and Marking System**



DST = CompnentType

10 = Forward Current (10A) 45 = Reverse Voltage (45V)

S = PackageType

A = AEC-Q101 Qualified Compnent

LF = Littelfuse
YY = Year
WW = Week
L = Lot Number

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